OSRAM V105Q131A-940 Datasheet

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BIDOS® P2433 Q

V105Q131A-940

940 nm Multi-Mode VCSEL Power Array Designed for Sensor Field of Interest : 72° x 58°





Applications

- 3D Sensing
- Access Control & Security
- Features
- Package: QFN Package
- ESD: 2 kV acc. to ANSI/ESDA/JEDEC JS-001 (HBM, Class 2)
- Very small SMT package
- VCSEL power array
- IR Laser with photodiode

- Eye, face and hand tracking



Ordering Information

$I_{_{\rm F}}$ = 4 A; $t_{_{\rm p}}$ = 300 µs; D = 0.05 ; $T_{_{\rm S}}$ = 25 °C			
Туре	Optical output power typ. $I_F = 4 \text{ A}; t_p = 300 \mu\text{s}; \text{ D} = 0.05 ; \text{ T}_S = 25 ^{\circ}\text{C}$ P_{opt}	Ordering Code	
V105Q131A-940	3 W	Q65113A1627	

Depending on the mode of operation, these devices emit highly concentrated visible and non-visible light which can be hazardous to the human eye. Products which incorporate these devices must follow the safety precautions given in the "Notes" section.



Maximum Ratings

T_A = 25 °C

T _{op} T _{stg}	min. max.	-20 °C
T _{stg}	max.	
T _{stg}		85 °C
	min.	-40 °C
	max.	100 °C
Ts	max.	260 °C
Vesd	max.	2 kV
Tj	max.	125 °C
I _{F pulse}	max.	6 A
VR	max.	Not designed for
		reverse operation
		· · · ·
VR	max.	20 V
	Ts VESD Tj IF pulse VR	max. Ts max. VESD max. Tj max. IF pulse max. VR max.

Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device.



Characteristics

t_p = 300 μs; D = 0.05; T_A = 25 °C

Parameter	Symbol		Values
IR Laser			
Peak wavelength ⁶⁾	λ_{peak}	min.	931 nm
-		typ.	940 nm
		max.	949 nm
Optical output power ⁷⁾	P _{opt}	min.	2.40 W
$I_F = 4 A$		typ.	3.00 W
Field of view (HFOV)	Θ	typ.	74 °
Angle at E _e ,50% level, normalized to the centroid			
Field of view (VFOV)	Θ_{\perp}	typ.	61 °
Angle at E _e ,50% level, normalized to the centroid			
Dimensions of chip area	L x W	typ.	0.9 x 1.0
			mm x mm
Slope efficiency	η	min.	0.70 W/ A
I _F = 1 A 2 A		typ.	0.85 W/ A
Power conversion efficiency	η _{tot}	typ.	36 %
$I_F = 4 A$			
Threshold current	l _{th}	typ.	0.5 A
		max.	0.7 A
Forward voltage ⁸⁾	VF	min.	1.95 V
$I_F = 4 A$		typ.	2.20 V
		max.	2.45 V
Rise time	t _r	typ.	1 ns
10% and 90% of I _{e max}			
Fall time	tf	typ.	1 ns
10% and 90% of I _{e max}			
Temperature coefficient of wavelength	TC_{λ}	typ.	0.07 nm/ K
Thermal resistance junction solder point real	R _{thJS real}	max.	11 K/ W
t _p = 0.01 s			



Characteristics

T_A = 25 °C

Parameter	Symbol	Symbol	
Photodiode			
Wavelength of max sensitivity	$\lambda_{S max}$	typ.	840 nm
Spectral range of sensitivity	λ _{10%}	typ.	400 1100 nm
Photocurrent $\lambda = 940 \text{ nm}, \text{ E}_{e} = 0.5 \text{ mW/cm}^{2}, \text{ V}_{R} = 3.3 \text{ V}$	lP	typ.	0.188 µA
Photocurrent with VCSEL @ I_F = 4 A, V_R = 3.3 V	lp	typ.	400 µA
Dimensions of chip area	LxW	typ.	0.38 x 0.38 mm x mm
Forward voltage $I_F = 10 \text{ mA}, \text{ E} = 0$	VF	typ. max.	0.85 V 1.00 V
Capacitance $E_e = 0 \text{ mW/cm}^2$, f = 1 MHz, $V_R = 0 \text{ V}$	Co	typ.	1.3 pF
Dark current $V_R = 3.3 V$	IR	typ. max.	0.1 nA 30 nA
Open-circuit voltage $\lambda = 940 \text{ nm}, \text{ E}_{e} = 0.5 \text{ mW/cm}^{2}$	Vo	typ.	260 mV
Short-circuit current $\lambda = 940 \text{ nm}, \text{ E}_{e} = 0.5 \text{ mW/cm}^{2}, \text{ V}_{R} = 0 \text{ V}$	Isc	typ.	188 nA
Rise time $\lambda = 940 \text{ nm}, \text{ V}_{\text{R}} = 0.7 \text{ V}, \text{ R}_{\text{L}} = 50 \Omega$	tr	typ.	205 ns
Fall time $\lambda = 940 \text{ nm}, \text{ V}_{\text{R}} = 0.7 \text{ V}, \text{ R}_{\text{L}} = 50 \Omega$	t _f	typ.	215 ns
Temperature coefficient of sensitivity $\lambda = 940 \text{ nm}, \text{ E}_e = 0.5 \text{ mW/cm}^2, \text{ V}_R = 3.3 \text{ V}$	T _{CI}	typ.	0.23 %/ K



Relative Spectral Emission ^{1), 2)}

• infrared (940 nm): I_{_{e,rel}} = f (λ); I_{_F} = 4000 mA; t_{_p} = 300 µs; D = 0.05



Radiation Characteristics 1), 2)

• infrared (940 nm): $E_{e,rel}$ = f (ϕ) ; I_F = 4 A; t_p = 300 µs; D = 0.05





Far-Field Illumination Pattern ²⁾

• infrared (940 nm): $I_{rel} = f(\phi); I_{F} = 4 \text{ A}; t_{p} = 300 \text{ }\mu\text{s}; \text{ D} = 0.05$



	Min	Тур	Max
1	100%	100%	100%
2	115%	138%	160%
3	125%	145%	165%
4	120%	143%	165%
5	125%	145%	165%
6	115%	138%	160%
7	125%	145%	165%
8	120%	143%	165%
9	125%	145%	165%
Α	70%	90%	110%
В	70%	90%	110%
С	70%	90%	110%
D	70%	90%	110%

Sensor FOI 72°(H) x 58°(V) (dotted line)



Relative Spectral Sensitivity ^{1), 2)}

• photodiode: $S_{rel} = f(\lambda); V_{R} = 3.3 V$



Optical Output Power 1), 2)

Forward Voltage ^{1), 2)}

• infrared (940 nm): $P_{opt} = f(I_F)$; $t_p = 300 \ \mu s$; D = 0.05



• infrared (940 nm): $V_{_F}$ = f (I_{_F}); t_{_p} = 300 µs; D = 0.05





Photocurrent ^{1), 2)}

• photodiode: $I_P = f(P_{opt})$



Dark Current 1), 2)

• photodiode: $I_R = f(V_R)$; E = 0



Capacitance 1), 2)

• photodiode: $C = f(V_R)$; f = 1MHz; E = 0





Dark Current ¹⁾

• photodiode: $I_R = f(T_A)$; E = 0; $V_R = 3.3 V$



Permissible Pulse Handling Capability

• infrared (940 nm): $I_F = f(t_p)$; D = param.; $T_S = 85^{\circ}C$; (not characterized for DC condition)





Dimensional Drawing³⁾



Further Information:

Approximate Weight:

20.0 mg



Recommended Solder Pad ³⁾









2.4

ĉ

Component Location on Pad

1,2



0.35

. 9.6

0.2 afloat 1,95



cathode VCSEL

anode VCSEL



E062.3010.294-03



OHA04525

s 300

*T*_D 245 °C

Reflow Soldering Profile

100

50

0

25 °C

50



100

Product complies to MSL Level 3 acc. to JEDEC J-STD-020E

All temperatures refer to the center of the package, measured on the top of the component

* slope calculation DT/Dt: Dt max. 5 s; fulfillment for the whole T-range

- t Pb-Free (SnAgCu) Assembly **Profile Feature** Symbol Unit Recommendation Minimum Maximum 2 3 Ramp-up rate to preheat*) K/s 25 °C to 150 °C Time t_s 60 100 ts 120 s $\rm T_{Smin}$ to $\rm T_{Smax}$ Ramp-up rate to peak*) 2 3 K/s T_{Smax} to T_{P} T_{L} °C Liquidus temperature 217 Time above liquidus temperature t, 80 100 s °C Peak temperature T_{P} 245 260 Time within 5 °C of the specified peak 10 20 t_P 30 s temperature $T_P - 5 K$ Ramp-down rate* 3 6 K/s $T_{_{\rm P}}$ to 100 $^\circ C$ Time 480 s 25 °C to T_{P}

150

200

250

V105Q131A-940 DATASHEET



Taping ³⁾



C67062-A0363-B6-04



Tape and Reel ⁴⁾



Reel Dimensions

А	W	N _{min}	W ₁	$W_{2 \max}$	Pieces per PU
180 mm	12 + 0.3 / - 0.1 mm	60 mm	12.4 + 2 mm	18.4 mm	2000



Barcode-Product-Label (BPL)



Dry Packing Process and Materials





Notes

Depending on the mode of operation, these devices emit highly concentrated visible and non visible light which can be hazardous to the human eye. Products which incorporate these devices have to follow the safety precautions given in IEC 60825-1.

Subcomponents of this device contain, in addition to other substances, metal filled materials including silver. Metal filled materials can be affected by environments that contain traces of aggressive substances. Therefore, we recommend that customers minimize device exposure to aggressive substances during storage, production, and use. Devices that showed visible discoloration when tested using the described tests above did show no performance deviations within failure limits during the stated test duration. Respective failure limits are described in the IEC60810.

For further application related information please visit https://ams-osram.com/support/application-notes



Disclaimer

Attention please!

The information describes the type of component and shall not be considered as assured characteristics. Terms of delivery and rights to change design reserved. Due to technical requirements components may contain dangerous substances.

For information on the types in question please contact our Sales Organization.

If printed or downloaded, please find the latest version on our website.

Packing

Please use the recycling operators known to you. We can also help you – get in touch with your nearest sales office. By agreement we will take packing material back, if it is sorted. You must bear the costs of transport. For packing material that is returned to us unsorted or which we are not obliged to accept, we shall have to invoice you for any costs incurred.

Product and functional safety devices/applications or medical devices/applications

Our components are not developed, constructed or tested for the application as safety relevant component or for the application in medical devices.

Our products are not qualified at module and system level for such application.

In case buyer – or customer supplied by buyer – considers using our components in product safety devices/ applications or medical devices/applications, buyer and/or customer has to inform our local sales partner immediately and we and buyer and /or customer will analyze and coordinate the customer-specific request between us and buyer and/or customer.



Glossary

- Typical Values: Due to the special conditions of the manufacturing processes of semiconductor devices, the typical data or calculated correlations of technical parameters can only reflect statistical figures. These do not necessarily correspond to the actual parameters of each single product, which could differ from the typical data and calculated correlations or the typical characteristic line. If requested, e.g. because of technical improvements, these typ. data will be changed without any further notice.
- 2) **Testing temperature:** $T_A = 25^{\circ}C$ (unless otherwise specified)
- 3) **Tolerance of Measure:** Unless otherwise noted in drawing, tolerances are specified with ±0.1 and dimensions are specified in mm.
- 4) Tape and Reel: All dimensions and tolerances are specified acc. IEC 60286-3 and specified in mm.
- 5) **Reverse Operation:** This product is intended to be operated applying a forward current within the specified range. Applying any continuous reverse bias or forward bias below the voltage range of light emission shall be avoided because it may cause migration which can change the electro-optical characteristics or damage the LED.
- 6) Wavelength: The wavelengths are measured with a tolerance of ±1 nm.
- 7) Brightness: The brightness values are measured with a tolerance of ±11%.
- 8) Forward Voltage: The forward voltages are measured with a tolerance of ±0.1 V.



Revision History

Version	Date	Change
1.0	2021-09-13	Initial Version
1.1	2023-05-04	Applications Maximum Ratings New Layout
1.2	2024-06-26	Recommended Solder Pad Taping
1.3	2025-02-04	Characteristics



EU RoHS and China RoHS compliant product 此产品符合欧盟 RoHS 指令的要求; 按照中国的相关法规和标准, 不含有毒有害物质或元素。

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